

THBT15011, THBT20011, THBT27011

Tripolar overvoltage protection for telecom line

Features

- Bidirectional crowbar protection between tip and gnd, ring and gnd and between tip and ring
- Peak pulse current: I_{PP} = 30 A for 10/1000 µs surge
- Holding current: I_H = 150 mA

Complies with Telcordia standards

- Telcordia GR-1089-Core, (second level) with line series resistors
 - 10/1000 μs, 1000 V
 - 2/10 μs, 2500 V (first level)
 - 2/10 µs, 5000 V

Description

Dedicated to telecommunication equipment protection, these devices provide a triple bidirectional protection function.

They ensure the same protection capability with the same breakdown voltage both in longitudinal mode and transversal mode.

A particular attention has been given to the internal wire bonding. The "4-point" configuration ensures a reliable protection, eliminating overvoltages introduced by the parasitic inductances of the wiring (Ldi/dt), especially for very fast transient overvoltages.

Dynamic characteristics have been defined for several types of surges, in order to meet the SLIC maximum ratings.

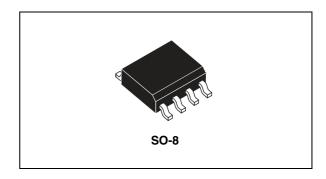
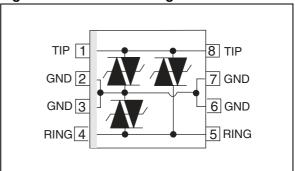


Figure 1. Schematic diagram



1 Characteristics

Table 1. Absolute maximum ratings ($T_{amb} = 25$ °C)

Symbol	Parameter	Value	Unit	
I _{PP}	Peak pulse current ⁽¹⁾	30	Α	
I _{TSM}	Non repetitive surge peak on-state current $(F = 50 \text{ Hz})$ $t = 10 \text{ r}$ $t = 1 \text{ s}$		8 3.5	Α
Tstg Tj	Storage temperature range Maximum junction temperature	- 40 to + 150 150	°C	
T _L	Maximum lead temperature for soldering du	260	°C	

^{1.} For pulse waveform see Figure 2

Figure 2. Pulse waveform $10/1000 \mu s$, $tr = 10 \mu s$, $tp = 1000 \mu s$

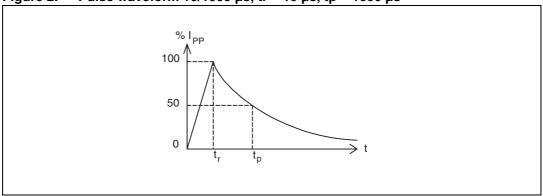


Figure 3. Test circuit for IPP

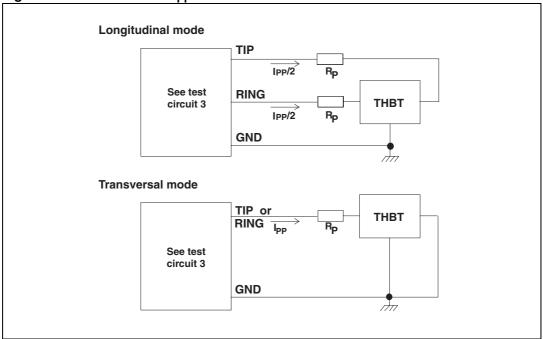


Table 2. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to ambient	170	°C/W

Table 3. Electrical characteristics ($T_{amb} = 25$ °C)

Symbol	Parameter
V _{RM}	Stand-off voltage
I _{RM}	Leakage current at stand-off voltage
V _R	Continuous reverse voltage
V _{BR}	Breakdown voltage
V _{BO}	Breakover voltage
I _H	Holding current
I _{BO}	Breakover current
V _F	Forward voltage drop
I _{PP}	Peak pulse current
С	Capacitance

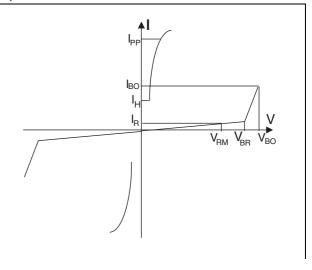


Table 4. Static parameters

	I _{RM} @ V _{RM}		I _R @	V _R	\	/ _{BO} @ I _B	0	I _H	С
Туре	max.		max.	1)	max.	min.		min. (3)	max. (4)
	μΑ	٧	μΑ	٧	٧	٧	mA	mA	pF
THBT15011D	5	135	50	150	210	50	400	150	80
THBT20011D	5	180	50	200	290	50	400	150	80
THBT27011D	5	240	50	270	380	50	400	150	80

- 1. I_R measured at V_R guarantee V_{BR} min $\geq V_R$
- 2. Measured at 50 Hz (1 cycle) See test circuit 1 (Figure 4).
- 3. See the reference test circuit 2 (Figure 5).
- 4. $V_R = 1 V \text{ bias}, V_{RMS} = 1 V, F = 1 MHz.$

Table 5. Dynamic breakover voltages (transversal mode)

Туре	Symbol		Max	Unit			
THBT15011D	V_{BO}	10/700μs 1.2/50μs 2/10μs	1.5kV 1.5kV 2.5kV	Rp=10 Ω Rp=10 Ω Rp=62 Ω	I _{PP} =30A I _{PP} =30A I _{PP} =38A	190 190 200	٧
THBT20011D	V _{BO}	10/700μs 1.2/50μs 2/10μs	1.5kV 1.5kV 2.5kV	Rp=10Ω Rp=10Ω Rp=62Ω	I _{PP} =30A I _{PP} =30A I _{PP} =38A	270 270 280	٧
THBT27011D	V _{BO}	10/700μs 1.2/50μs 2/10μs	1.5kV 1.5kV 2.5kV	Rp=10Ω Rp=10Ω Rp=62Ω	I _{PP} =30A I _{PP} =30A I _{PP} =38A	360 360 400	V

^{1.} See test circuit 3 for V_{BO} dynamic parameters; R_p is the protection resistor located on the line card.

Figure 4. Test circuit 1 for I_{BO} and V_{BO} parameters

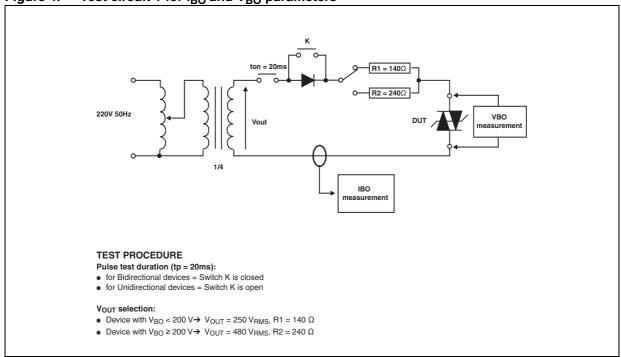


Figure 5. Test circuit 2 for I_H parameter

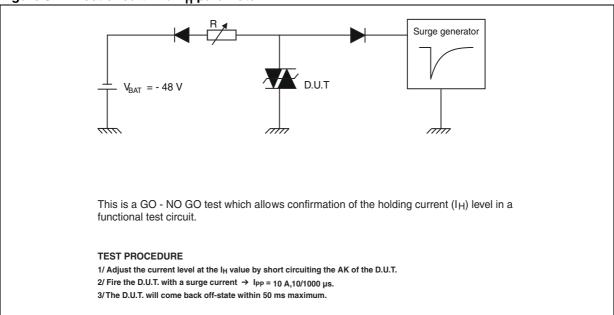


Figure 6. Test circuit 3 for V_{BO} parameters

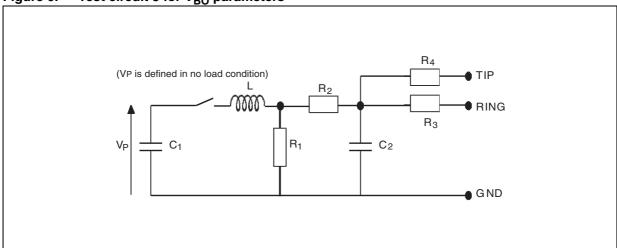


Table 6. Parameters for selected pulse characteristics

Pulse	e (µs)	V _p	C ₁	C ₂	L	R ₁	R ₂	R ₃	R ₄	I _{PP}	Rp
tr	tp	(V)	(μ F)	(nF)	(µH)	(Ω)	(Ω)	(Ω)	(Ω)	(A)	(Ω)
10	700	1500	20	200	0	50	15	25	25	30	10
1.2	50	1500	1	33	0	76	13	25	25	30	10
2	10	2500	10	0	1.1	1.3	0	3	3	38	62

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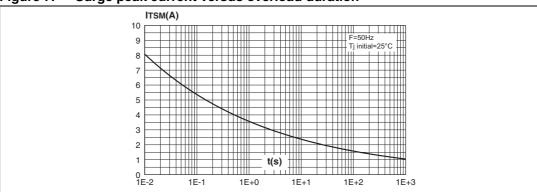
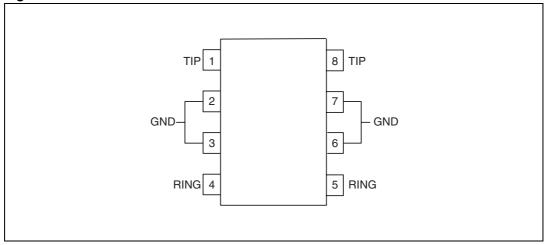


Figure 7. Surge peak current versus overload duration

2 Application information

Figure 8. Device connections



- 1. Connect pins 2, 3, 6 and 7 to Ground to guarantee a good surge current capability for long duration disturbances.
- 2. To take advantage of the "4-point" structure of the THBT, the TIP and RING lines have to cross the device. In this case, the device will eliminate the overvoltages generated by the parasitic inductances of the wiring (Ldi/dt), especially for very fast transients.

2.1 Application circuits

Figure 9. Line card protection

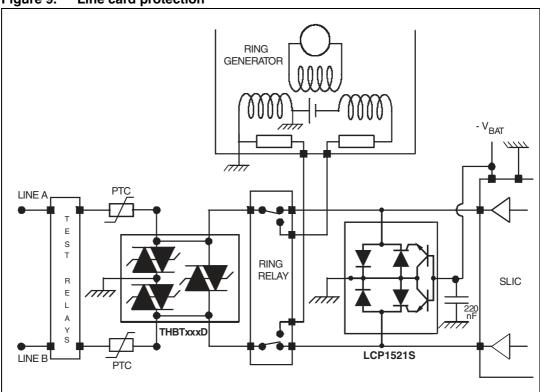
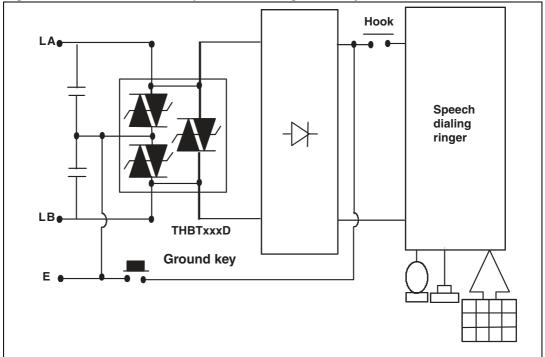


Figure 10. Protection for telephone set with ground key



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3 Package information

Epoxy meets UL94, V0

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at www.st.com.

Table 7. SO-8 dimensions

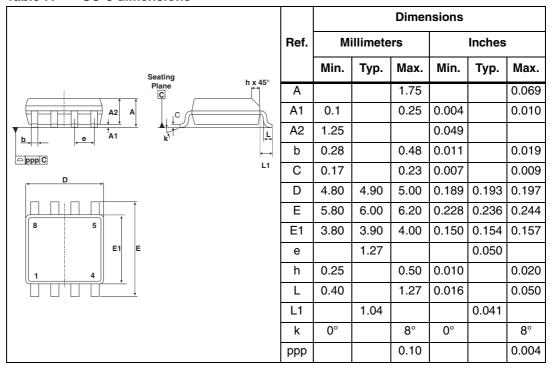
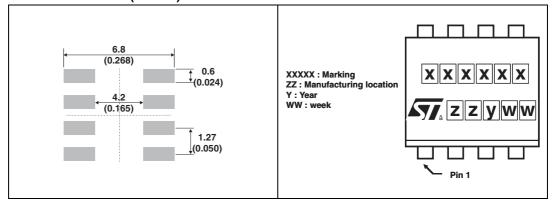


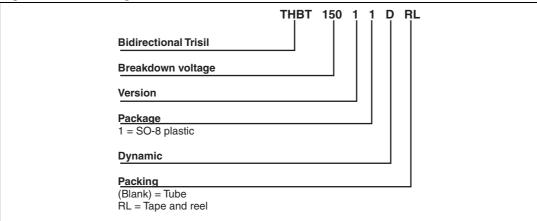
Figure 11. Footprint dimensions in mm (inches)

Figure 12. Marking



4 Ordering information scheme

Figure 13. Ordering information scheme



5 Ordering information

Table 8. Ordering information

Order code Marking		Package	Weight
THBT15011D	BT151D		
THBT20011D	THBT20011D BT201D		0.077 g
THBT27011D	BT271D		

6 Revision history

Table 9. Document revision history

Table of Document Totalen Incidery							
Date	Revision	Changes					
Oct-2003	7A	Previous release					
19-Feb-2008	8	Reformatted to current standards. Removed THBT16011D from <i>Table 4</i> and <i>Table 8</i> . Updated <i>Figure 4</i> , <i>Figure 5</i> , and <i>Figure 9</i> . Added ECOPACK paragraph in <i>Section 3</i> . Added <i>Figure 12: Marking</i> .					

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